

Product Specification

PE9701

3000 MHz UltraCMOS™ Integer-N PLL Rad Hard for Space Applications

Features

- 3.0 GHz operation
- ÷10/11 dual modulus prescaler
- Internal phase detector with charge pump
- Serial, parallel or hardwired programmable
- Ultra-low phase noise
- SEU < 10⁻⁹ errors / bit-day
- 100 Krad (Si) total dose
- 44-lead CQFJ

Product Description

Peregrine's PE9701 is a high-performance integer-N PLL capable of frequency synthesis up to 3.0 GHz. The device is designed for superior phase noise performance while providing an order of magnitude reduction in current consumption, when compared with existing commercial space PLLs.

The PE9701 features a 10/11 dual modulus prescaler. counters, and a phase comparator as shown in Figure 1. Counter values are programmable through either a serial or parallel interface and can also be directly hard wired.

The PE9701 is optimized for commercial space applications. Single Event Latch up (SEL) is physically impossible and Single Event Upset (SEU) is better than 10⁻⁹ errors per bit / day. It is manufactured on Peregrine's UltraCMOS™ process, a patented variation of silicon-oninsulator (SOI) technology on a sapphire substrate, offering excellent RF performance and intrinsic radiation tolerance.

Figure 1. Block Diagram

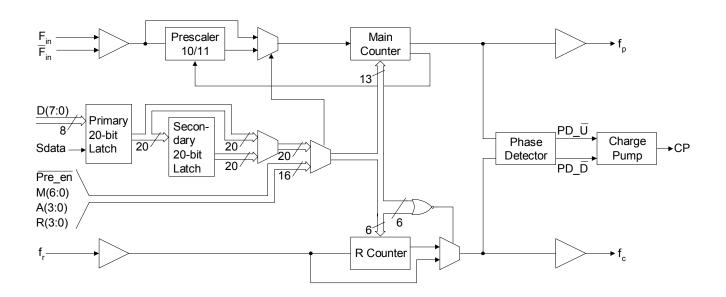


Figure 2. Pin Configurations (Top View)

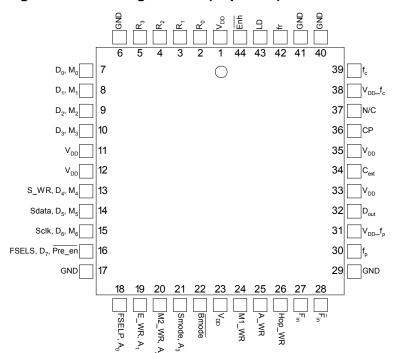


Figure 3. Package Type 44-lead CQFJ



Table 1. Pin Descriptions

| Pin No. | Pin Name | Interface Mode | Type | Description |
|----------------------------|-----------------|----------------|------------------------|---|
| 1 | V _{DD} | ALL | (Note 1) | Power supply input. Input may range from 2.85 V to 3.15 V. Bypassing recommended. |
| 2 | R ₀ | Direct | Input | R Counter bit0 (LSB). |
| 3 | R ₁ | Direct | Input | R Counter bit1. |
| 4 | R ₂ | Direct | Input | R Counter bit2. |
| 5 | R ₃ | Direct | Input | R Counter bit3. |
| 6 | GND | ALL | (Note 1) | Ground. |
| _ | D ₀ | Parallel | Input | Parallel data bus bit0 (LSB). |
| 7 | M ₀ | Direct | Input | M Counter bit0 (LSB). |
| 8 | D ₁ | Parallel | Input | Parallel data bus bit1. |
| | M ₁ | Direct | Input | M Counter bit1. |
| 9 | D ₂ | Parallel | Input | Parallel data bus bit2. |
| | M ₂ | Direct | Input | M Counter bit2. |
| 10 | D ₃ | Parallel | Input | Parallel data bus bit3. |
| | M ₃ | Direct | Input | M Counter bit3. |
| 11 | V _{DD} | ALL | (Note 1) | Same as pin 1. |
| 12 | V _{DD} | ALL | (Note 1) | Same as pin 1. |
| 42 | S_WR | Serial | Input | Serial load enable input. While S_WR is "low", Sdata can be serially clocked. Primary register data is transferred to the secondary register on S_WR or Hop_WR rising edge. |
| D ₄ Parallel Ir | | Input | Parallel data bus bit4 | |
| | M ₄ | Direct | Input | M Counter bit4 |



Table 1. Pin Descriptions (continued)

| Pin No. | Pin Name | Interface Mode | Туре | Description |
|---------|---------------------|------------------|----------|--|
| | Sdata | Serial | Input | Binary serial data input. Input data entered MSB first. |
| 14 | D ₅ | Parallel | Input | Parallel data bus bit5. |
| | M ₅ | Direct | Input | M Counter bit5. |
| | Sclk | Serial | Input | Serial clock input. Sdata is clocked serially into the 20-bit primary register (E_WR "low") or the 8-bit enhancement register (E_WR "high") on the rising edge of Sclk. |
| 15 | D ₆ | Parallel | Input | Parallel data bus bit6. |
| | M ₆ | Direct | Input | M Counter bit6. |
| | FSELS | Serial | Input | Selects contents of primary register (FSELS=1) or secondary register (FSELS=0) for programming of internal counters while in Serial Interface Mode. |
| 16 | D ₇ | Parallel | Input | Parallel data bus bit7 (MSB). |
| | Pre_en | Direct | Input | Prescaler enable, active "low". When "high", F _{in} bypasses the prescaler. |
| 17 | GND | ALL | | Ground. |
| 18 | FSELP | Parallel | Input | Selects contents of primary register (FSELP=1) or secondary register (FSELP=0) for programming of internal counters while in Parallel Interface Mode. |
| 10 | A ₀ | Direct | Input | A Counter bit0 (LSB). |
| | 5 | Serial | Input | Enhancement register write enable. While E_WR is "high", Sdata can be serially clocked into the enhancement register on the rising edge of Sclk. |
| 19 | E_WR | Parallel | Input | Enhancement register write. D[7:0] are latched into the enhancement register on the rising edge of E_WR. |
| | A ₁ | Direct | Input | A Counter bit1. |
| 20 | M2_WR | Parallel | Input | M2 write. D[3:0] are latched into the primary register (R[5:4], M[8:7]) on the rising edge of M2_WR. |
| 20 | A ₂ | Direct | Input | A Counter bit2. |
| 21 | Smode | Serial, Parallel | Input | Selects serial bus interface mode (Bmode=0, Smode=1) or Parallel Interface Mode (Bmode=0, Smode=0). |
| 21 | A ₃ | Direct | Input | A Counter bit3 (MSB). |
| 22 | Bmode | ALL | Input | Selects direct interface mode (Bmode=1). |
| 23 | V _{DD} | ALL | (Note 1) | Same as pin 1. |
| 24 | M1_WR | Parallel | Input | M1 write. D[7:0] are latched into the primary register (Pre_en, M[6:0]) on the rising edge of M1 WR. |
| 25 | A_WR | Parallel | Input | A write. D[7:0] are latched into the primary register (R[3:0], A[3:0]) on the rising edge of A_WR. |
| 26 | Hop_WR | Serial, Parallel | Input | Hop write. The contents of the primary register are latched into the secondary register on the rising edge of Hop_WR. |
| 27 | F _{in} | ALL | Input | Prescaler input from the VCO. 3.0 GHz max frequency. |
| 28 | $\overline{F_{in}}$ | ALL | Input | Prescaler complementary input. A bypass capacitor in series with a 51 Ω resistor should be placed as close as possible to this pin and be connected directly to the ground plane. |
| 29 | GND | ALL | | Ground. |
| 30 | f _p | ALL | Output | Monitor pin for main divider output. Switching activity can be disabled through enhancement register programming or by floating or grounding V_{DD} pin 31. |

Table 1. Pin Descriptions (continued)

| Pin No. | Pin Name | Interface Mode | Туре | Description |
|---------|---------------------------------|---------------------|---------------|---|
| 31 | V _{DD} -f _p | ALL | (Note 1) | V _{DD} for f _p |
| 32 | Dout | ut Serial, Parallel | | Data Out. The MSEL signal and the raw prescaler output are available on Dout through enhancement register programming. |
| 33 | V _{DD} | ALL | (Note 1) | Same as pin 1. |
| 34 | Cext | ALL | Output | Logical "OR" of PD_U and PD_D terminated through an on chip, $2 \ k\Omega$ series resistor. Connecting Cext to an external capacitor will low pass filter the input to the inverting amplifier used for driving LD. |
| 35 | V _{DD} | ALL | (Note 1) | Same as pin 1. |
| 36 | СР | ALL | Output | Charge pump current is sourced for "up" when f_c leads f_p and sinked for "down" when f_c lags f_p . |
| 37 | NC | ALL | | No connection. |
| 38 | V _{DD} -f _c | ALL | (Note 1) | V _{DD} for f _c |
| 39 | f _c | ALL | Output | Monitor pin for reference divider output. Switching activity can be disabled through enhancement register programming or by floating or grounding V_{DD} pin 38. |
| 40 | GND | ALL | | Ground. |
| 41 | GND | ALL | | Ground. |
| 42 | f _r | ALL | Input | Reference frequency input. |
| 43 | LD | ALL | Output, OD | Lock detect and open drain logical inversion of Cext. When the loop is in lock, LD is high impedance, otherwise LD is a logic low ("0"). |
| 44 | Enh | Serial, Parallel | Input | Enhancement mode. When asserted low ("0"), enhancement register bits are functional. |

Note 1: V_{DD} pins 1, 11, 12, 23, 31, 33, 35, and 38 are connected by diodes and must be supplied with the same positive voltage level. $\ensuremath{V_{\text{DD}}}$ pins 31 and 38 are used to enable test modes and should be left floating.

Note 2: All digital input pins have 70 k Ω pull-down resistors to ground.



Table 2. Absolute Maximum Ratings

| Symbol | Parameter/Conditions | Min | Max | Units |
|-----------|---------------------------|------|--------------------------|-------|
| V_{DD} | Supply voltage | -0.3 | 4.0 | V |
| Vı | Voltage on any input | -0.3 | V _{DD} + 0.3 | V |
| I | DC into any input | -10 | +10 | mA |
| Io | DC into any output | -10 | +10 | mA |
| T_{stg} | Storage temperature range | -65 | 150 | °C |

Table 3. Operating Ratings

| Symbol | Parameter/Conditions | Min | Max | Units |
|----------------|-------------------------------------|------|------|-------|
| V_{DD} | Supply voltage | 2.85 | 3.15 | V |
| T _A | Operating ambient temperature range | -40 | 85 | °C |

Table 4. ESD Ratings

| Symbol | Parameter/Conditions | Level | Units |
|------------------|--|-------|-------|
| V _{ESD} | ESD voltage (Human Body Model) – Note 1 | 1000 | V |

Note 1: Periodically sampled, not 100% tested. Tested per MIL-STD-883, M3015 C2

Electrostatic Discharge (ESD) Precautions

When handling this UltraCMOS™ device, observe the same precautions that you would use with other ESD-sensitive devices. Although this device contains circuitry to protect it from damage due to ESD, precautions should be taken to avoid exceeding the specified rating in Table 4.

Latch-Up Avoidance

Unlike conventional CMOS devices, UltraCMOS™ devices are immune to latch-up.

Table 5. DC Characteristics: $V_{DD} = 3.0 \text{ V}$, $-40^{\circ} \text{ C} < T_A < 85^{\circ} \text{ C}$, unless otherwise specified

| Symbol | Parameter | Conditions | Min | Тур | Max | Units |
|--|--|---|-----------------------|----------|-----------------------|----------|
| I _{DD} | Operational supply current; Prescaler disabled Prescaler enabled | V _{DD} = 2.85 to 3.15 V | | 10 24 | 31 | mA mA |
| Digital Inputs: | All except f _r , F _{in} , F _{in} | • | | | | |
| V _{IH} | High level input voltage | $V_{DD} = 2.85 \text{ to } 3.15 \text{ V}$ | 0.7 x V _{DD} | | | V |
| V _{IL} | Low level input voltage | $V_{DD} = 2.85 \text{ to } 3.15 \text{ V}$ | | | 0.3 x V _{DD} | V |
| I _{IH} | High level input current | $V_{IH} = V_{DD} = 3.15 \text{ V}$ | | | +70 | μA |
| I _{IL} | Low level input current | $V_{IL} = 0, V_{DD} = 3.15 \text{ V}$ | -1 | | | μA |
| Reference Div | ider input: f _r | 1 | 1 | | | |
| I _{IHR} | High level input current | $V_{IH} = V_{DD} = 3.15 \text{ V}$ | | | +100 | μΑ |
| I _{ILR} | Low level input current | $V_{IL} = 0, V_{DD} = 3.15 \text{ V}$ | -100 | | | μA |
| R0 Input: R₀ | | 1 | | | | |
| I _{IHRO} | High level input current | $V_{IH} = V_{DD} = 3.15 \text{ V}$ | | | +70 | μA |
| I _{ILRO} | Low level input current | $V_{IL} = 0, V_{DD} = 3.15 \text{ V}$ | -5 | | | μA |
| Counter and p | hase detector outputs: f _c , f _p . | 1 | | | | |
| V _{OLD} | Output voltage LOW | I _{out} = 6 mA | | | 0.4 | V |
| V _{OHD} | Output voltage HIGH | I _{out} = -3 mA | V _{DD} - 0.4 | | | V |
| Lock detect ou | utputs: Cext, LD | 1 | | | | |
| V _{OLC} | Output voltage LOW, Cext | I _{out} = 100 μA | | | 0.4 | V |
| V _{OHC} | Output voltage HIGH, Cext | I _{out} = -100 μA | V _{DD} - 0.4 | | | V |
| V _{OLLD} | Output voltage LOW, LD | I _{out} = 6 mA | | | 0.4 | V |
| Charge Pump | output: CP | 1 | | | | |
| I _{CP} - Source | Drive current | $V_{CP} = V_{DD} / 2$ | -2.6 | -2 | -1.4 | mA |
| I _{CP} – Sink | Drive current | $V_{CP} = V_{DD} / 2$ | 1.4 | 2 | 2.6 | mA |
| I _{CPL} | Leakage current | 1.0 V < V _{CP} < V _{DD} - 1.0 V | -1 | | 1 | μA |
| I _{CP} – Source vs. I _{CP} Sink | Sink vs. source mismatch | $VCP = V_{DD} / 2,$ $T_A = 25^{\circ} C$ | | | 25 | % |
| I _{CP} vs. V _{CP} | Output current magnitude variation vs. voltage | $V < V_{CP} < V_{DD} - 1.0 V$ $T_A = 25^{\circ} C$ | | | 25 | % |



Table 6. AC Characteristics: $V_{DD} = 3.0 \text{ V}$, $-40^{\circ} \text{ C} < T_A < 85^{\circ} \text{ C}$, unless otherwise specified

| Symbol | Parameter | Conditions | Min | Max | Units |
|-------------------|--|------------------------|-----|------|-------|
| Control Interface | e and Latches (see Figures 4, 5, 6) | | | | |
| f _{Clk} | Serial data clock frequency | (Note 1) | | 10 | MHz |
| t _{ClkH} | Serial clock HIGH time | | 30 | | ns |
| t _{ClkL} | Serial clock LOW time | | 30 | | ns |
| t _{DSU} | Sdata hold time after Sclk rising edge, D[7:0] set-up time to M1_WR, M2_WR, A_WR, E_WR rising edge | | 10 | | ns |
| t _{DHLD} | Sdata hold time after Sclk rising edge, D[7:0] hold time to M1_WR, M2_WR, A_WR, E_WR rising edge | | 10 | | ns |
| t _{PW} | S_WR, M1_WR, M2_WR, A_WR, E_WR pulse width | | 30 | | ns |
| t _{CWR} | Sclk rising edge to S_WR rising edge. S_WR, M1_WR, M2_WR, A_WR falling edge to Hop_WR rising edge | | 30 | | ns |
| t _{CE} | Sclk falling edge to E_WR transition | | 30 | | ns |
| t _{WRC} | S_WR falling edge to Sclk rising edge. Hop_WR falling edge to S_WR, M1_WR, M2_WR, A_WR rising edge | | 30 | | ns |
| t _{EC} | E_WR transition to Sclk rising edge | | 30 | | ns |
| t _{MDO} | MSEL data out delay after Fin rising edge | C _L = 12 pf | | 8 | ns |
| Main Divider (Pr | escaler Enabled) | | | | |
| F _{in} | Operating frequency | | 500 | 3000 | MHz |
| P _{Fin} | Input level range | External AC coupling | -5 | 5 | dBm |
| Main Divider (Pr | rescaler Bypassed) | | | | |
| F _{in} | Operating frequency | | 50 | 300 | MHz |
| P _{Fin} | Input level range | External AC coupling | -5 | 5 | dBm |
| Reference Divid | er | | | | |
| f _r | Operating frequency | (Note 3) | | 100 | MHz |
| P _{fr} | Reference input power (Note 2) | Single-ended input | -2 | | dBm |
| Phase Detector | | | | | |
| f _c | Comparison frequency | (Note 3) | | 20 | MHz |

Note 1: Fclk is verified during the functional pattern test. Serial programming sections of the functional pattern are clocked at 10 MHz to verify Fclk specification.

Note 2: CMOS logic levels can be used to drive reference input if DC coupled. Voltage input needs to be a minimum of 0.5 V_{p-p}.

Note 3: Parameter is guaranteed through characterization only, and is not tested.

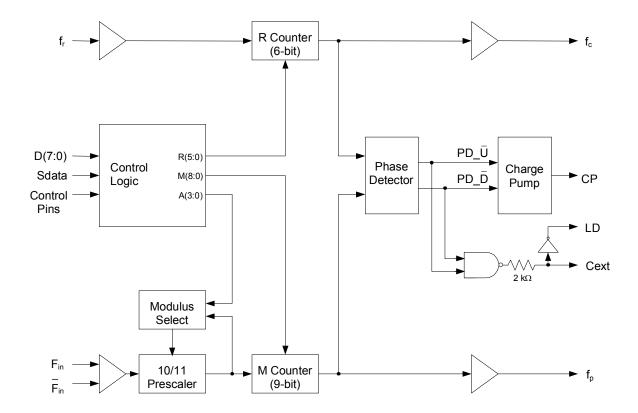


Functional Description

The PE9701 consists of a prescaler, counters, a phase detector, a charge pump, and control logic. The dual modulus prescaler divides the VCO frequency by either 10 or 11, depending on the value of the modulus select. Counters "R" and "M" divide the reference and prescaler output, respectively, by integer values stored in a 20-bit register. An additional counter ("A") is used in the modulus select logic. The phase-frequency

detector generates up and down frequency control signals. The control logic includes a selectable chip interface. Data can be written via serial bus, parallel bus, or hardwired directly to the pins. There are also various operational and test modes and a lock detect output.

Figure 4. Functional Block Diagram





Main Counter Chain

Normal Operating Mode

The main counter chain divides the RF input frequency, Fin, by an integer derived from the user-defined values in the "M" and "A" counters. It is composed of the 10/11 dual modulus prescaler. modulus select logic, and 9-bit M counter. Setting Pre en "low" enables the 10/11 prescaler. Setting Pre en "high" allows F_{in} to bypass the prescaler and powers down the prescaler.

The output from the main counter chain, f_p, is related to the VCO frequency, Fin, by the following equation:

$$f_p = F_{in} / [10 \times (M + 1) + A]$$
 (1)
where $A \le M + 1$, $1 \le M \le 511$

When the loop is locked, Fin is related to the reference frequency, f_r, by the following equation:

$$F_{in} = [10 \times (M + 1) + A] \times (f_r / (R+1))$$
 (2)
where $A \le M + 1$, $1 \le M \le 511$

A consequence of the upper limit on A is that Fin must be greater than or equal to 90 x (f_r / (R+1)) to obtain contiguous channels. Programming the M Counter with the minimum value of "1" will result in a minimum M Counter divide ratio of "2".

In Direct Interface Mode, main counter inputs M₇ and M₈ are internally forced low. In this mode, the M value is limited to $1 \le M \le 127$.

Prescaler Bypass Mode

Setting Pre en "high" allows Fin to bypass and power down the prescaler. In this mode, the 10/11 prescaler and A register are not active, and the input VCO frequency is divided by the M counter directly. The following equation relates Fin to the reference frequency, fr:

$$F_{in} = (M + 1) \times (f_r / (R+1))$$
 (3) where $1 \le M \le 511$

In Direct Interface Mode, main counter inputs M₇ and M₈ are internally forced low. In this mode, the M value is limited to $1 \le M \le 127$.

Reference Counter

The reference counter chain divides the reference frequency, f_r, down to the phase detector comparison frequency, f_c.

The output frequency of the 6-bit R Counter is related to the reference frequency by the following equation:

$$f_c = f_r / (R + 1)$$
 (4)
where $0 \le R \le 63$

Note that programming R with "0" will pass the reference frequency, f_r, directly to the phase detector.

In Direct Interface Mode, R Counter inputs R₄ and R₅ are internally forced low ("0"). In this mode, the R value is limited to $0 \le R \le 15$.

Register Programming

Parallel Interface Mode

Parallel Interface Mode is selected by setting the Bmode input "low" and the Smode input "low".

Parallel input data, D[7:0], is latched in a parallel fashion into one of three 8-bit primary register sections on the rising edge of M1 WR, M2 WR, or A_WR per the mapping shown in Table 7 on page 9. The contents of the primary register are transferred into a secondary register on the rising edge of Hop_WR according to the timing diagram shown in Figure 5. Data is transferred to the counters as shown in Table 7 on page 9.

The secondary register acts as a buffer to allow rapid changes to the VCO frequency. This double buffering for "ping-pong" counter control is programmed via the FSELP input. When FSELP is "high", the primary register contents set the counter inputs. When FSELP is "low", the secondary register contents are utilized.

Parallel input data, D[7:0], is latched into the enhancement register on the rising edge of E WR according to the timing diagram shown in Figure 5. This data provides control bits as shown in Table 8 on page 9 with bit functionality enabled by asserting the Enh input "low"



Serial Interface Mode

Serial Interface Mode is selected by setting the Bmode input "low" and the Smode input "high".

While the E WR input is "low" and the S_WR input is "low", serial input data (Sdata input), Bo to B₁₉, is clocked serially into the primary register on the rising edge of Sclk, MSB (B₀) first. The contents from the primary register are transferred into the secondary register on the rising edge of either S_WR or Hop_WR according to the timing diagram shown in Figure 6. Data is transferred to the counters as shown in Table 7 on page 9.

The double buffering provided by the primary and secondary registers allows for "ping-pong" counter control using the FSELS input. When FSELS is "high", the primary register contents set the counter inputs. When FSELS is "low", the secondary register contents are utilized.

While the E_WR input is "high" and the S_WR input is "low", serial input data (Sdata input), B₀ to

B₇, is clocked serially into the enhancement register on the rising edge of Sclk, MSB (B₀) first. The enhancement register is double buffered to prevent inadvertent control changes during serial loading, with buffer capture of the serially-entered data performed on the falling edge of E_WR according to the timing diagram shown in Figure 6. After the falling edge of E WR, the data provides control bits as shown in Table 8 with bit functionality enabled by asserting the Enh input "low".

Direct Interface Mode

Direct Interface Mode is selected by setting the Bmode input "high".

Counter control bits are set directly at the pins as shown in Table 7. In Direct Interface Mode, main counter inputs M₇ and M₈, and R Counter inputs R₄ and R₅ are internally forced low ("0").

Table 7. Primary Register Programming

| Interface Mode | Enh | Bmode | Smode | R₅ | R ₄ | M ₈ | M ₇ | Pre_en | M ₆ | M ₅ | M ₄ | M ₃ | M ₂ | M ₁ | Mo | R ₃ | R ₂ | R₁ | R₀ | A ₃ | A ₂ | A ₁ | A ₀ |
|-------------------|--------------|-------|-------|----------------|----------------|----------------|----------------|------------------------|----------------|----------------|----------------|----------------|-----------------------|-----------------|-----------------|-----------------|-----------------|-----------------|-----------------|-----------------------|-----------------|-----------------------|-----------------|
| Dorollol | 1 | 0 | 0 | M2_V | VR risir | ng edge | load | M1_WR rising edge load | | | | | A_WR rising edge load | | | | | | | | | | |
| Faranei | Parallel 1 0 | 0 | D_3 | D_2 | D ₁ | D ₀ | D ₇ | D_6 | D ₅ | D_4 | D_3 | D ₂ | D ₁ | D ₀ | D ₇ | D_6 | D ₅ | D ₄ | D_3 | D_2 | D ₁ | D ₀ | |
| Serial* | 1 | 0 | 1 | B ₀ | B ₁ | B ₂ | B ₃ | B ₄ | B ₅ | B ₆ | B ₇ | B ₈ | B ₉ | B ₁₀ | B ₁₁ | B ₁₂ | B ₁₃ | B ₁₄ | B ₁₅ | B ₁₆ | B ₁₇ | B ₁₈ | B ₁₉ |
| Direct | 1 | 1 | Х | 0 | 0 | 0 | 0 | Pre_en | M_6 | M_5 | M_4 | M_3 | M ₂ | M ₁ | M _o | R_3 | R ₂ | R ₁ | R_0 | A_3 | A_2 | A ₁ | A ₀ |

^{*}Serial data clocked serially on Sclk rising edge while E_WR "low" and captured in secondary register on S_WR rising edge.

MSB (first in) (last in) LSB

Table 8. Enhancement Register Programming

| Interface Mode | Enh | Bmode | Smode | Reserved | Reserved | Reserved | Power down | Counter load | MSEL output | Prescaler output | f _c , f _p OE | | |
|-------------------|-----|-------|-------|----------------|-----------------------|----------------|---------------|-----------------|----------------|------------------|------------------------------------|--|--|
| Parallel | 0 | 0 | 0 | | E_WR rising edge load | | | | | | | | |
| Parallel | | 0 | 0 | D ₇ | D ₆ | D ₅ | D_4 | D ₃ | D_2 | D ₁ | D ₀ | | |
| Serial* | 0 | 0 | 1 | B_0 | B ₁ | B_2 | B_3 | B ₄ | B_{5} | B_6 | B ₇ | | |

^{*}Serial data clocked serially on Sclk rising edge while E_WR "high" and captured in the double buffer on E_WR falling edge.



Figure 5. Parallel Interface Mode Timing Diagram

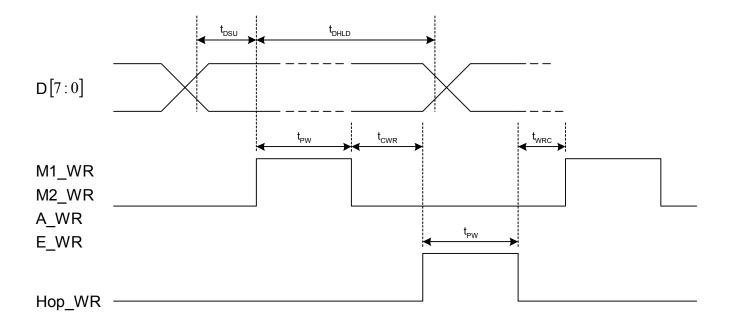
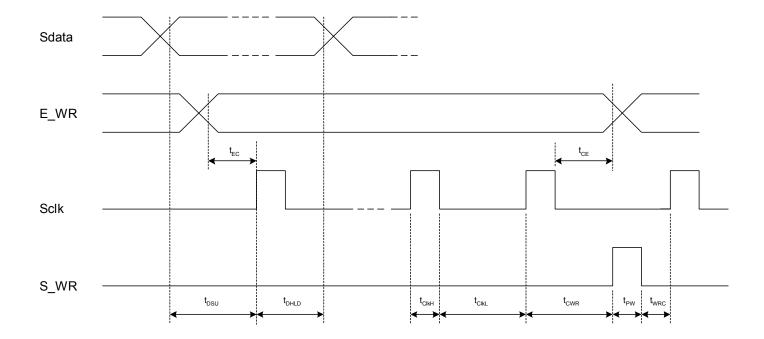


Figure 6. Serial Interface Mode Timing Diagram





Enhancement Register

The functions of the enhancement register bits are shown below with all bits active "high".

Table 9. Enhancement Register Bit Functionality

| Ві | it Function | Description |
|-------|------------------|---|
| Bit 0 | Reserved** | |
| Bit 1 | Reserved** | |
| Bit 2 | Reserved** | |
| Bit 3 | Power down | Power down of all functions except programming interface. |
| Bit 4 | Counter load | Immediate and continuous load of counter programming as directed by the Bmode and Smode inputs. |
| Bit 5 | MSEL output | Drives the internal dual modulus prescaler modulus select (MSEL) onto the Dout output. |
| Bit 6 | Prescaler output | Drives the raw internal prescaler output (fmain) onto the Dout output. |
| Bit 7 | f_p , f_c OE | f_p , f_c outputs disabled. |

^{**} Program to 0

Phase Detector

The phase detector is triggered by rising edges from the main Counter (f_p) and the reference counter (f_c). It has two outputs, namely PD U, and PD D. If the divided VCO leads the divided reference in phase or frequency (f_p leads f_c), PD D pulses "high". If the divided reference leads the divided VCO in phase or frequency (f, leads f_p), PD U pulses "high". The width of either pulse is directly proportional to phase offset between the two input signals, fp and fc.

The signals from the phase detector couple directly to a charge pump. PD U controls a current source at pin CP with constant amplitude and pulse duration approximately the same as PD U. PD D similarly drives a current sink at

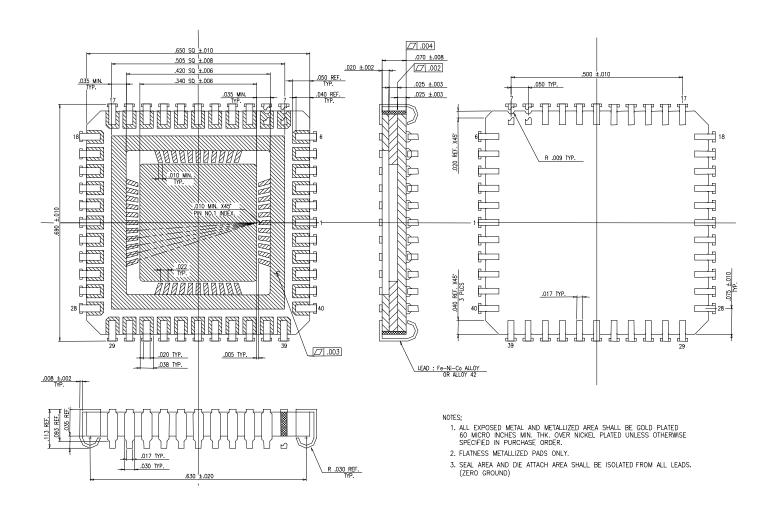
pin CP. The current pulses from pin CP are low pass filtered externally and then connected to the VCO tune voltage. PD_U pulses result in a current source, which increases the VCO frequency; PD D pulses result in a current sink, which decreases VCO frequency.

A lock detect output, LD is also provided, via the pin Cext. Cext is the logical "NAND" of PD U and PD D waveforms, which is driven through a series $2k \Omega$ resistor. Connecting Cext to an external shunt capacitor provides integration. Cext also drives the input of an internal inverting comparator with an open drain output. Thus LD is an "AND" function of PD U and PD D. See Figure 4 for a schematic of this circuit.



Figure 9. Package Drawing

44-lead CQFJ



All dimensions are in mils

Table 10. Ordering Information

| Order Code | Part Marking | Description | Package | Shipping Method | |
|------------|--------------|---------------------|-------------|-----------------|--|
| 9701-01 | PE9701 ES | Engineering Samples | 44-pin CQFJ | 40 units / Tray | |
| 9701-11 | PE9701 | Flight Units | 44-pin CQFJ | 40 units / Tray | |
| 9701-00 | PE9701 EK | Evaluation Kit | | 1 / Box | |



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Data Sheet Identification

Advance Information

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